



Superior Efficacy & Lumen output

Z Power LED – Z5-M4 Blue

S1CH-3535450003-00000000-00004 **Royal Blue(455)**

S1CH-3535470003-00000000-00004 **Blue(470)**



Product Brief

Description

- The Z-Power series is designed for high flux output applications with high current operation capability.
- It incorporates state of the art SMD design and low thermal resistant material.
- The Z Power LED is ideal source for high flux blue light source such as Horticulture, Landscape, and various outdoor applications.

Features and Benefits

- High Flux Output and High Efficacy
- Designed for high current operation
- Low Thermal Resistance
- SMT solder able
- Lead Free Product
- RoHS compliant

Key Applications

- Horticulture
- Architectural
- Projector light source
- Commercial

**Table 1. Product Selection (Order Code Table)**

Reference Codes	Color	Typical Wavelength	Part Number
SZ5-M4-B0-00	Royal Blue	455 nm	S1CH-3535450003-00000000-00004
SZ5-M4-B1-00	Blue	470 nm	S1CH-3535470003-00000000-00004



Table of Contents

Index	
• Product Brief	1
• Table of Contents	3
• Performance Characteristics	4
• Characteristics Graph	7
• Mechanical Dimensions	14
• Recommended Solder Pad	15
• Reflow Soldering Characteristics	16
• Emitter Tape & Reel Packaging	17
• Packaging Information	18
• Product Nomenclature	19
• Handling of Silicone Resin for LEDs	20
• Precaution For Use	21
• Company Information	24



Performance Characteristics

Table 2. Characteristics at 700mA (Ta=25°C, RH30%)

Parameter	Symbol	Value			Unit	
		Min.	Typ.	Max.		
Radiant Power (@Royal Blue) [1]	Φ_E	-	1370	-	mW	
Luminous Flux (@Blue) [1]	Φ_V	-	75	-	lm	
Dominant Wavelength	λ_D	Royal Blue	445	-	460	nm
		Blue	465	-	475	nm
PPF [2] (@Royal Blue)	Φ_p	-	5.23	-	$\mu\text{mol/s}$	
PPE [3] (@Royal Blue)	K_p	-	2.50	-	$\mu\text{mol/J}$	
Forward Voltage [4]	V_F	2.75	3.05	3.25	V	
Viewing angle	θ	125			degree	
Thermal resistance (J to S) [5]	$R\theta_{J-S}$	-	3.0	-	K/W	

Table 3. Absolute Maximum Ratings

Parameter	Symbol	Value			Unit
		Min.	Typ.	Max. [7]	
Forward Current	I_F	-	700	1400	mA
Reverse Voltage	V_R	-	-	5	V
Junction Temperature	T_j	-	-	135	°C
Storage Temperature	T_{stg}	- 10	-	85	°C
ESD Sensitivity(HBM) [6]	Class 3B JEDEC JS-001-2017				

Notes :

- (1) SSC maintains a tolerance of $\pm 7\%$ on power measurements.
- (2) Photosynthetic Photon Flux includes wavelengths between 400 and 700 nm.
- (3) Photosynthetic Photon Efficacy includes wavelengths between 400 and 700 nm.
- (4) Tolerance is $\pm 0.06\text{V}$ on forward voltage measurements
- (5) $R\theta_{J-S}$ is tested at 700mA.
- (6) The zener diode is included to protect the product from ESD
- (7) It is recommended to use it in the condition that the reliability is secured within the Max value.

- Thermal resistance can be increased substantially depending on the heat sink design/operating condition, and the maximum possible driving current will decrease accordingly.



Performance Characteristics

Table 3-1. Bin Code Description - Royal Blue (455), $I_F=700\text{mA}$, $T_a=25^\circ\text{C}$

Bin Code		
Radiant Power (mW) @ $I_F=700\text{mA}$	Dominant Wavelength (nm) @ $I_F=700\text{mA}$	Forward Voltage (V) @ $I_F=700\text{mA}$
M41	B13	G0

↓

Radiant Power (mW) ⁽¹⁾ @ $I_F=700\text{mA}$		
Bin Code	Min.	Max.
M32	1,250	1,300
M41	1,300	1,350
M42	1,350	1,400
P11	1,400	1,460
P12	1,460	1,520

↓

Dominant Wavelength (nm) @ $I_F=700\text{mA}$		
Bin Code	Min.	Max.
B13	445	450
B14	450	455
B15	455	460

↓

Forward Voltage (V) ⁽²⁾ @ $I_F=700\text{mA}$		
Bin Code	Min.	Max.
F2	2.55	2.75
G0	2.75	2.95
G1	2.95	3.15

Table 4. Brightness Groups

Part no	Color	Typical Wavelength [nm]	Flux Rank	R-Flux [mW]		PPF ⁽³⁾ [$\mu\text{mol/s}$]		PPF/W [$\mu\text{mol/J}$]
				min	Max	min	max	typ
SZ5-M4-B0-00	Royal Blue	455	M32	1250	1300	4.75	4.94	2.32
			M41	1300	1350	4.94	5.13	2.41
			M42	1350	1400	5.13	5.32	2.50
			P11	1400	1460	5.32	5.55	2.60
			P12	1460	1520	5.55	5.78	2.71

Notes : (1) Seoul Semiconductor maintains a tolerance of $\pm 7\%$ on flux and power measurements.

(2) Tolerance is $\pm 0.06\text{V}$ on forward voltage measurements

(3) Photosynthetic Photon Flux includes wavelengths between 400 and 700 nm



Performance Characteristics

Table 3-2. Bin Code Description - Blue (470), $I_F=700\text{mA}$, $T_a=25^\circ\text{C}$

Bin Code		
Luminous Flux (lm) @ $I_F=700\text{mA}$	Dominant Wavelength (nm) @ $I_F=700\text{mA}$	Forward Voltage (V) @ $I_F=700\text{mA}$
S1	B21	G0

↓

Luminous Flux (lm) ⁽¹⁾ @ $I_F=700\text{mA}$			
Bin Code	Min.	Max.	
R6	65	70	
S1	70	78	
S2	78	86	
S3	86	94	

↓

Dominant Wavelength (nm) @ $I_F=700\text{mA}$			
Bin Code	Min.	Max.	
B21	460	465	
B22	465	470	
B23	470	475	

↓

Forward Voltage (V) ⁽²⁾ @ $I_F=700\text{mA}$			
Bin Code	Min.	Max.	
F2	2.55	2.75	
G0	2.75	2.95	
G1	2.95	3.15	

- Notes :** (1) Seoul Semiconductor maintains a tolerance of $\pm 7\%$ on flux and power measurements.
 (2) Tolerance is $\pm 0.06\text{V}$ on forward voltage measurements



Characteristics Graph

Fig 1. Color Spectrum, $T_a=25^\circ\text{C}$

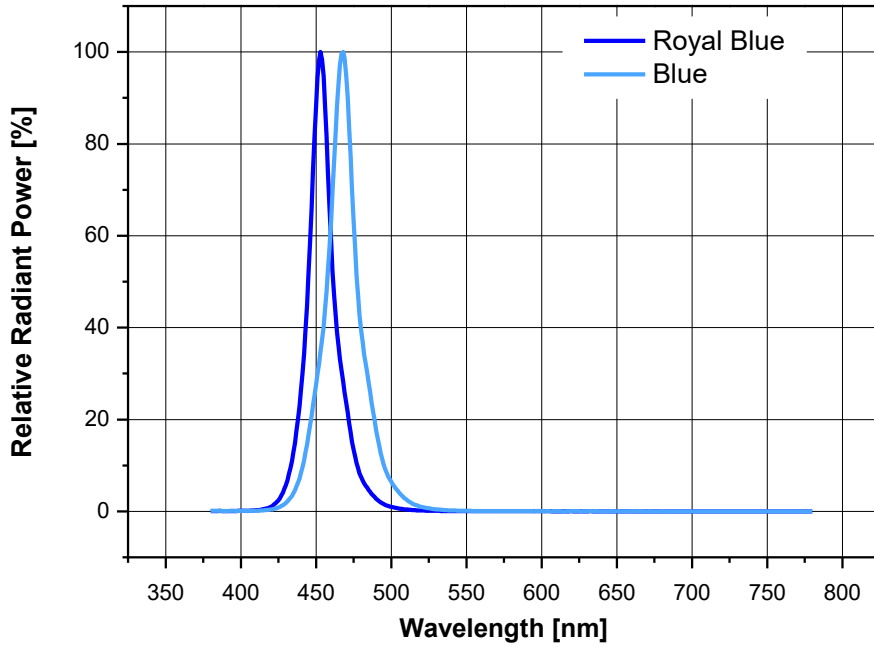
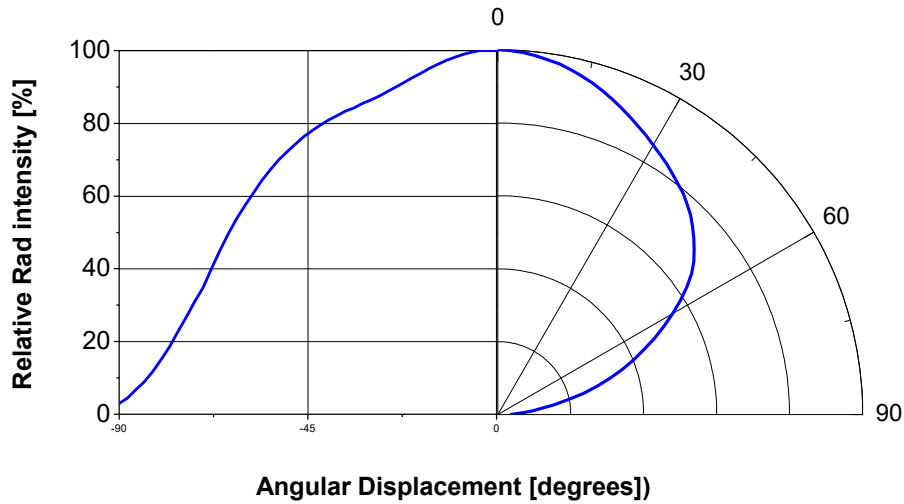


Fig 2. Typical Spatial Distribution, $T_a=25^\circ\text{C}$





Characteristics Graph

Fig 3. Forward Voltage vs. Forward Current, $T_a=25^{\circ}\text{C}$

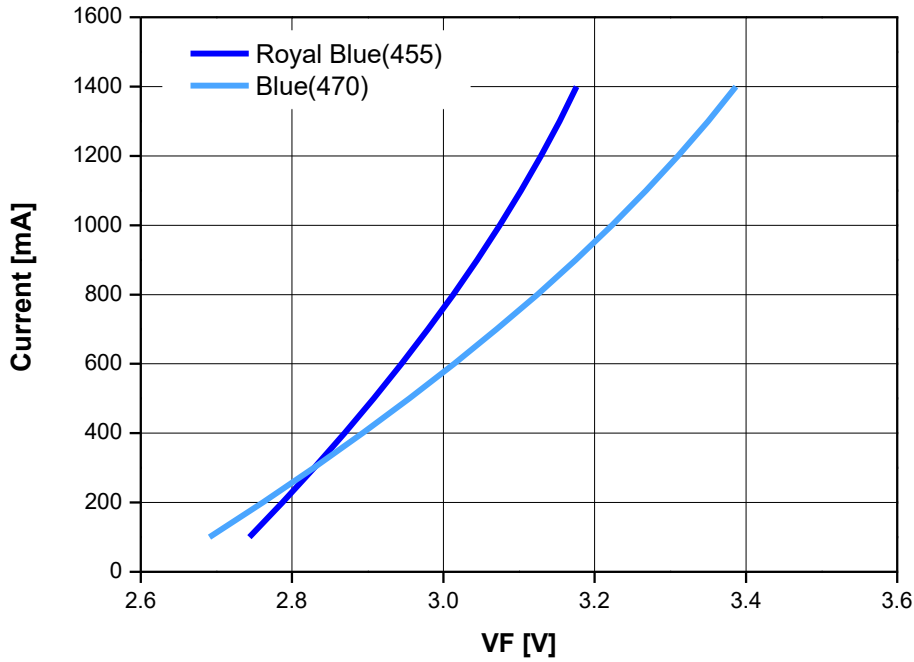
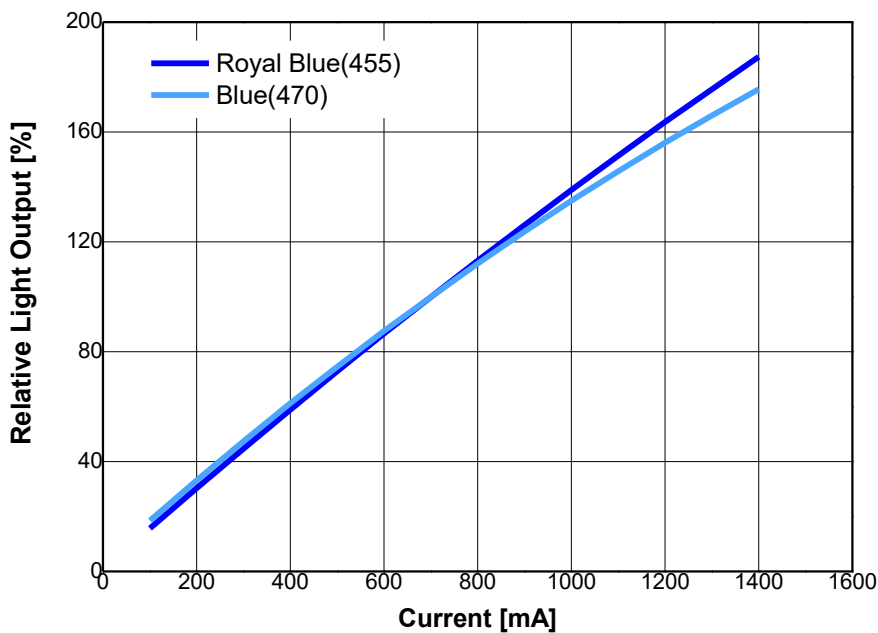


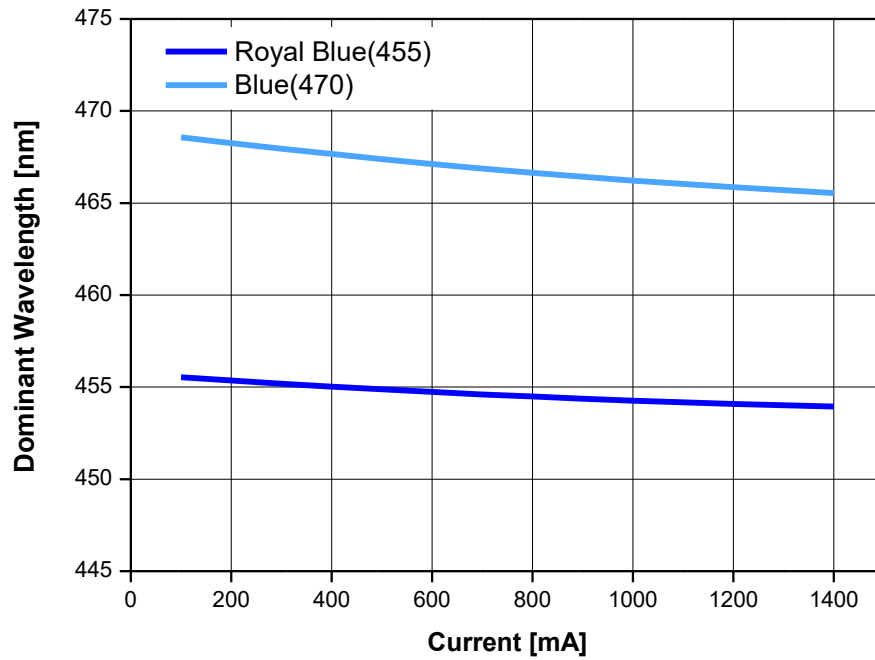
Fig 4. Forward Current vs. Relative Light Output, $T_a=25^{\circ}\text{C}$





Characteristics Graph

Fig 5. Forward Current vs. Dominant Wavelength, $T_a=25^{\circ}\text{C}$

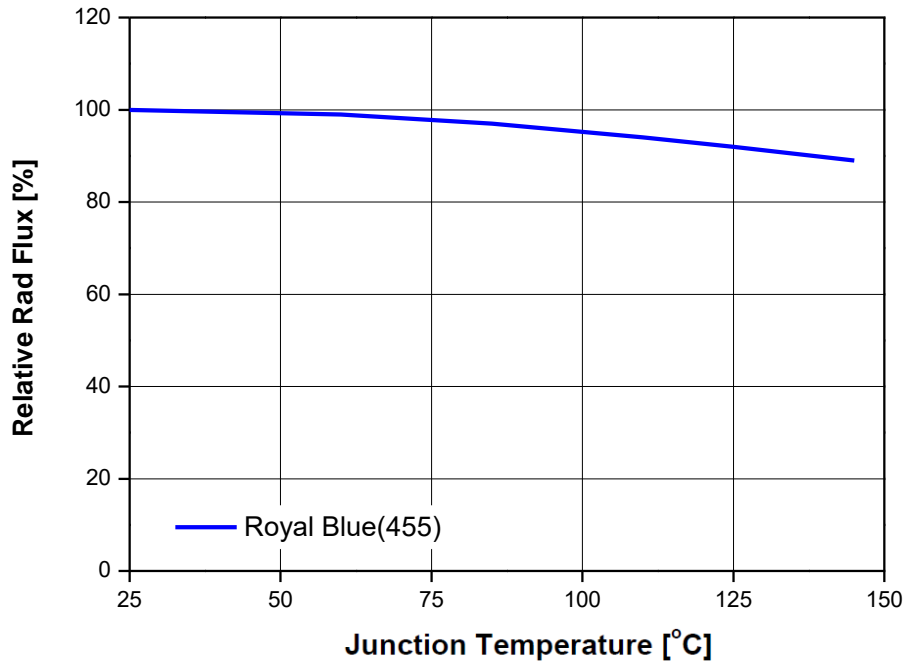




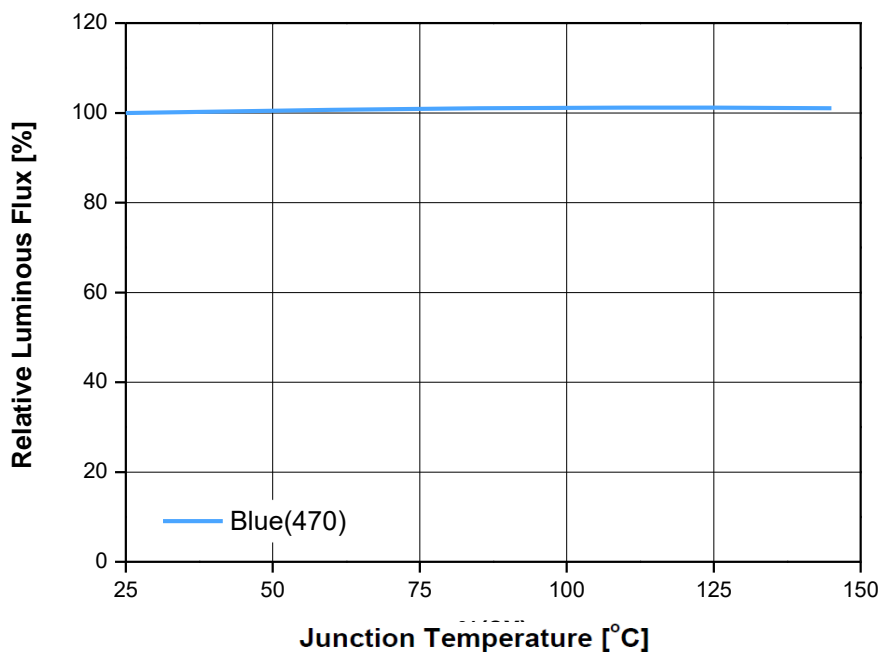
Characteristics Graph

Fig 6. Relative Light Output vs. Junction Temperature, $I_F=700mA$

SZ5-M4-B0-00(455nm Royal Blue)



SZ5-M4-B1-00(470nm Blue)





Characteristics Graph

Fig 7. Relative Forward Voltage vs. Junction Temperature, $I_F=700\text{mA}$

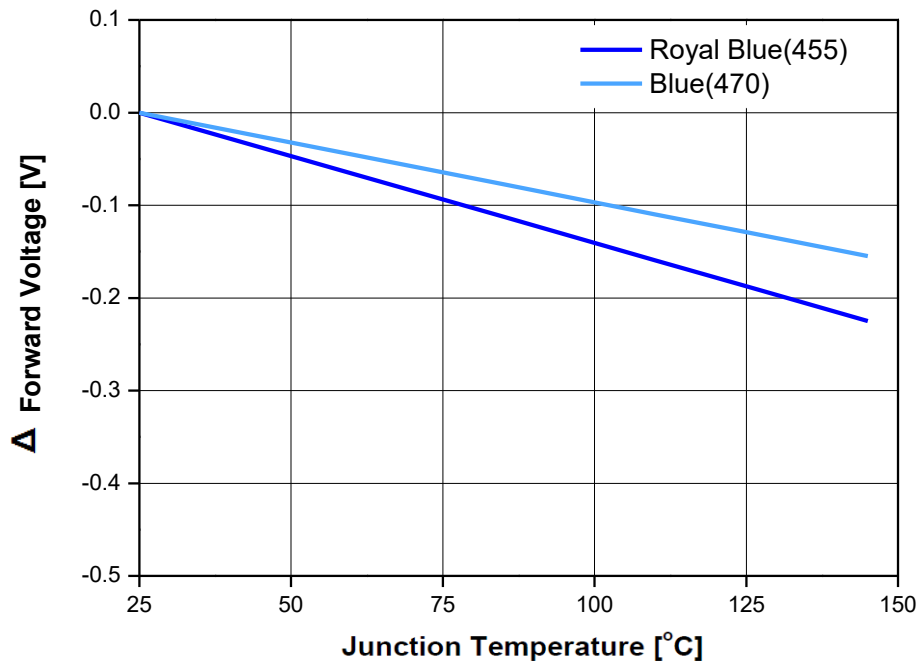
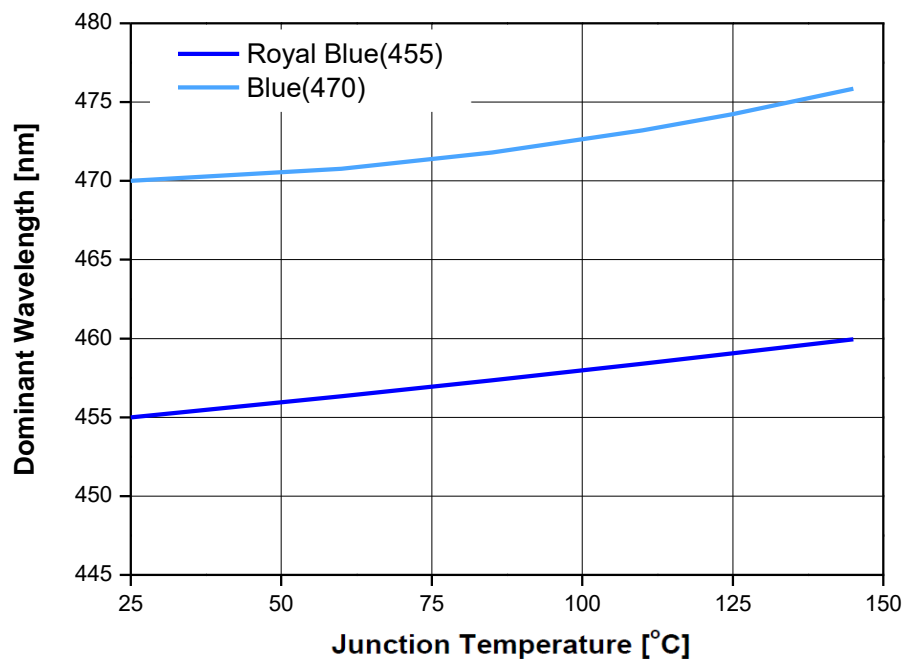


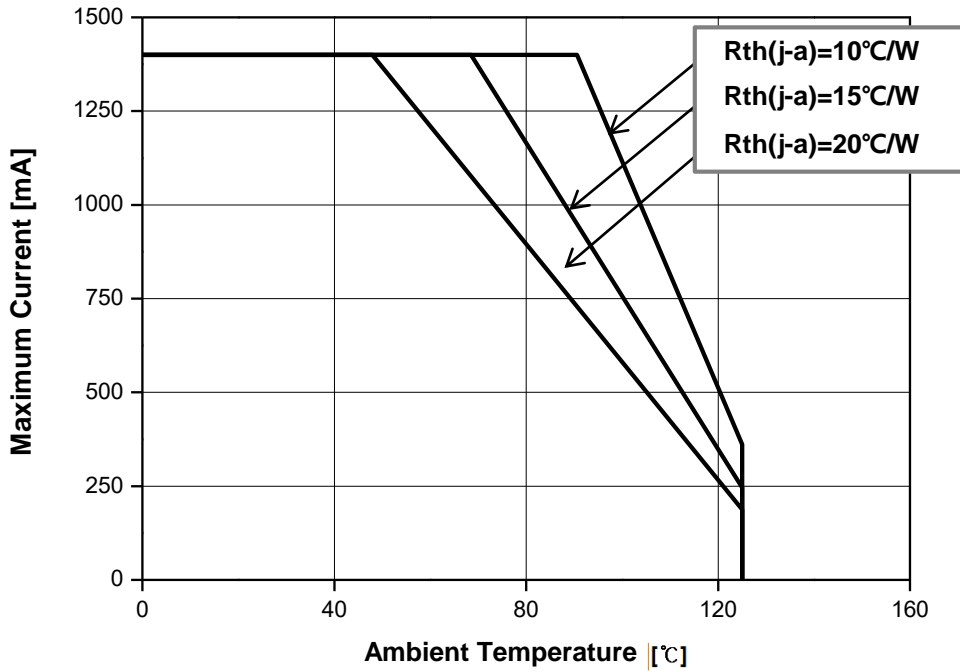
Fig 8. Junction Temperature vs. Dominant Wavelength, $I_F=700\text{mA}$





Characteristics Graph

Fig 9. Maximum Forward Current vs. Ambient Temperature, $T_j(\text{max.})=135^\circ\text{C}$





Characteristics Graph

Fig 10-1. Current vs $\mu\text{mol/s}$ characteristics

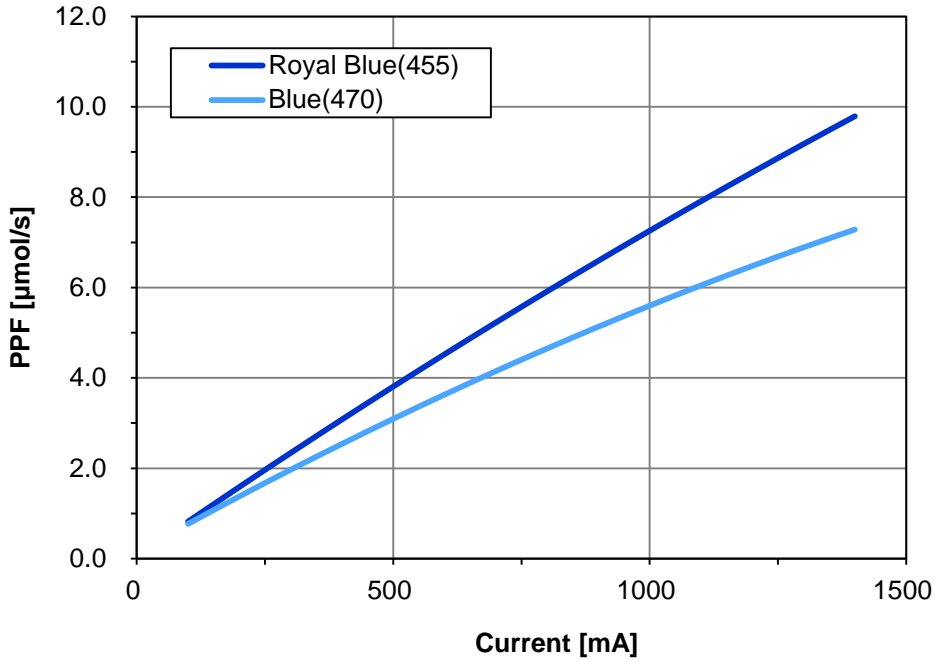


Fig 10-1. Current vs $\mu\text{mol/J}$ characteristics

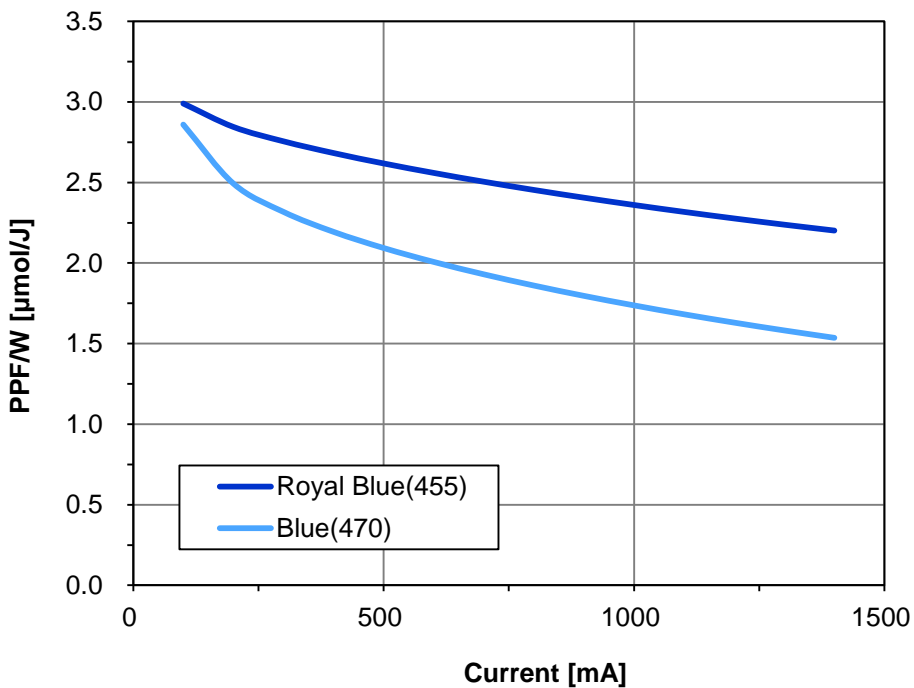
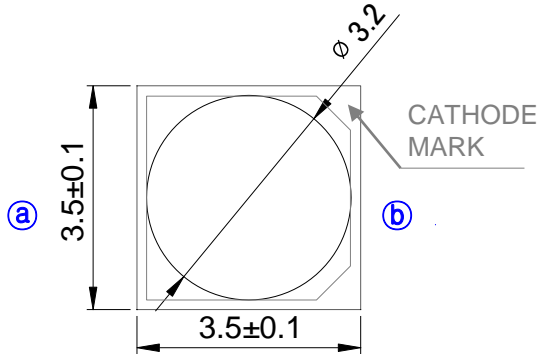


Fig 10-2. Current vs $\mu\text{mol/J}$ characteristics

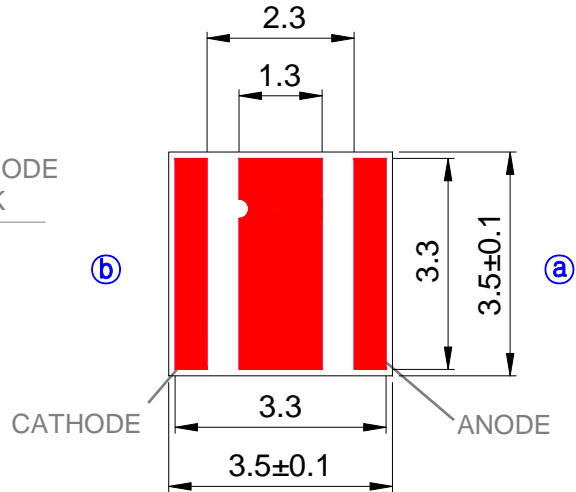


Mechanical Dimensions

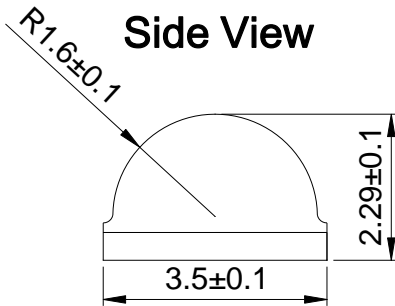
Top View



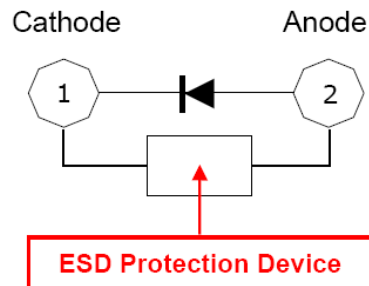
Bottom View



Side View



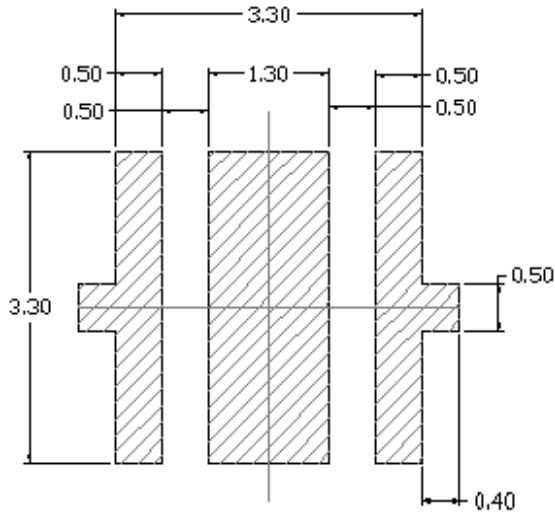
Circuit



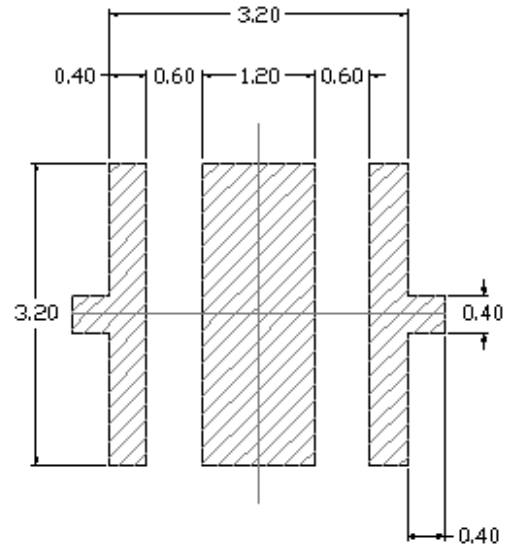
- (1) All dimensions are in millimeters.
- (2) Scale : none
- (3) Undefined tolerance is ± 0.1 mm



Recommended Solder Pad



Recommended PCB Solder Pad

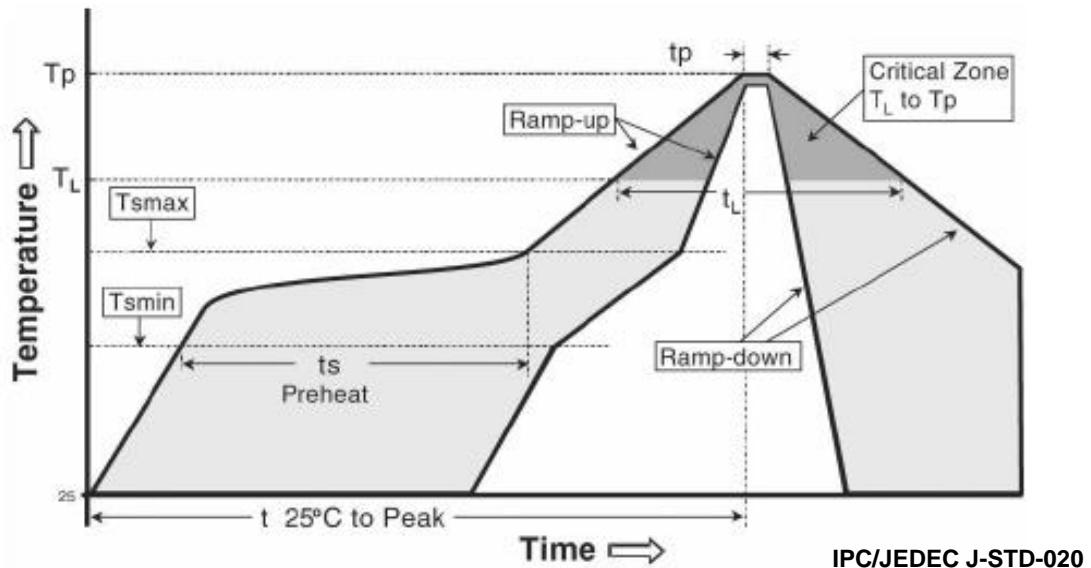


Recommended Stencil Pattern

- (1) All dimensions are in millimeters.
- (2) Scale : none
- (3) This drawing without tolerances are for reference only.
- (4) Undefined tolerance is $\pm 0.1\text{mm}$.



Reflow Soldering Characteristics



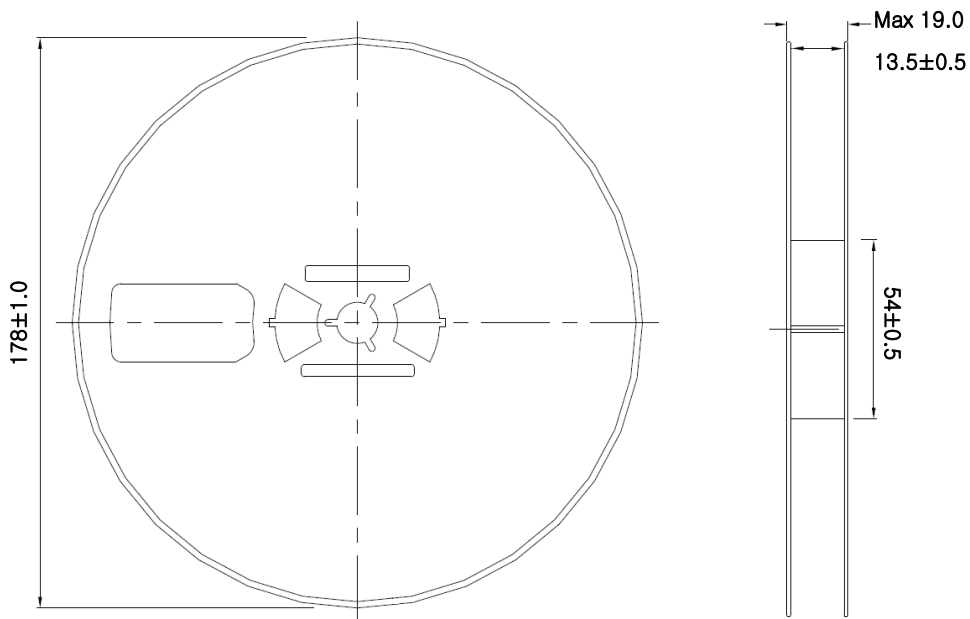
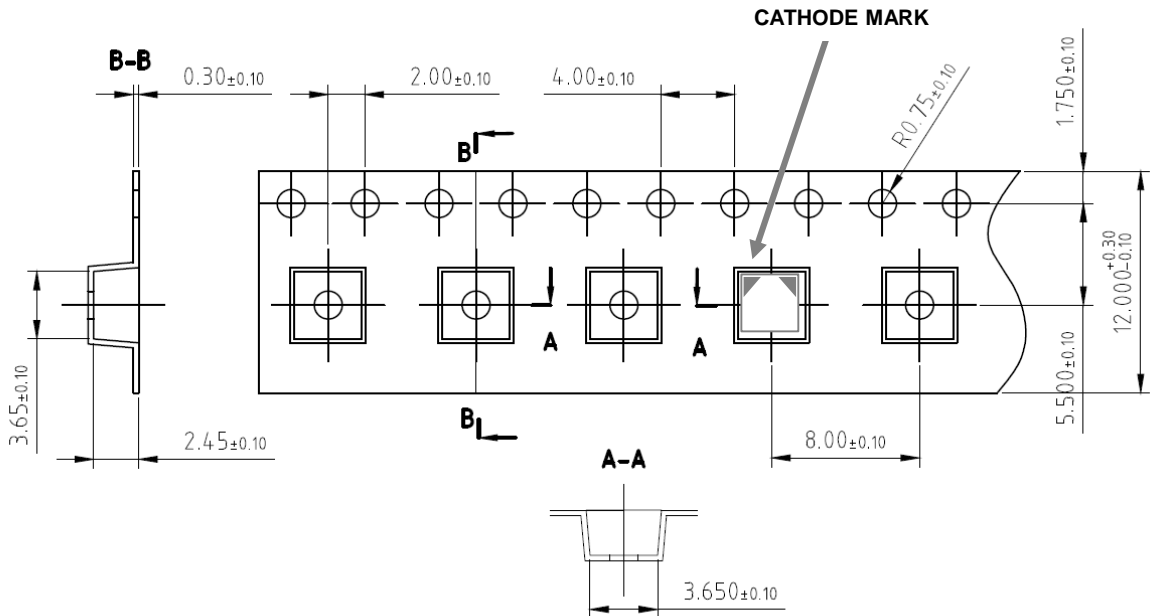
Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate (Tsmx to Tps)	3° C/second max.	3° C/second max.
Preheat		
- Temperature Min (Tsm)	100 °C	150 °C
- Temperature Max (Tsmx)	150 °C	200 °C
- Time (Tsm to Tsmx) (ts)	60-120 seconds	60-180 seconds
Time maintained above:		
- Temperature (Tl)	183 °C	217 °C
- Time (tL)	60-150 seconds	60-150 seconds
Peak Temperature (Tps)	215°C	260°C
Time within 5°C of actual Peak Temperature (tp)2	10-30 seconds	20-40 seconds
Ramp-down Rate	6 °C/second max.	6 °C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

Caution

- (1) Reflow soldering is recommended not to be done more than two times. In the case of more than 24 hours passed soldering after first, LEDs will be damaged.
- (2) Repairs should not be done after the LEDs have been soldered. When repair is unavoidable, suitable tools must be used.
- (3) Die slug is to be soldered.
- (4) When soldering, do not put stress on the LEDs during heating.
- (5) After soldering, do not warp the circuit board.



Emitter Tape & Reel Packaging



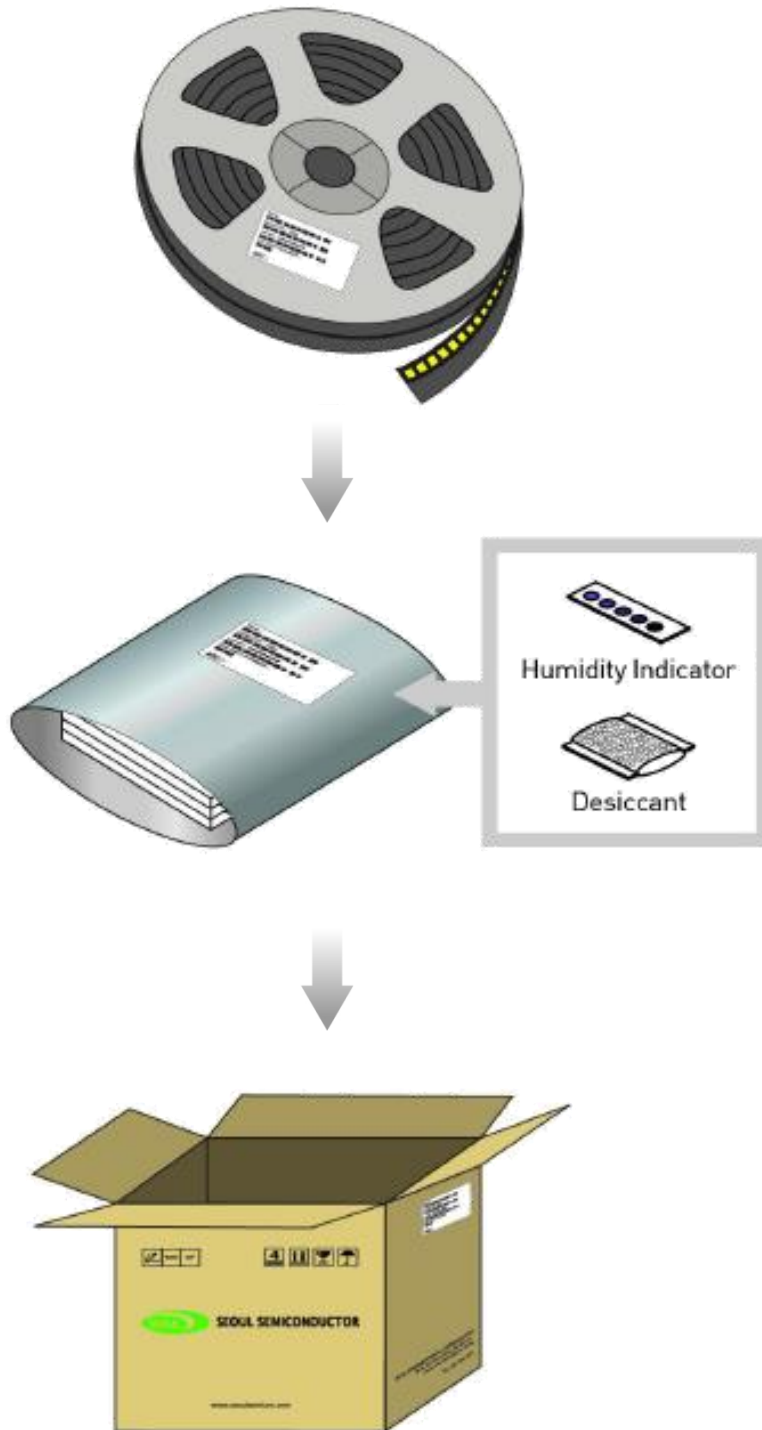
Notes :

UNIT: mm

- Quantity : 900pcs/Reel
- Cumulative Tolerance : Cumulative Tolerance/10 pitches to be ±0.2mm
- Adhesion Strength of Cover Tape : Adhesion strength to be 10-60g when the cover tape is turned off from the carrier tape at the angle of 10° to the carrier tape
- Package : P/N, Manufacturing data Code No. and quantity to be indicated on a damp proof Package



Packaging Information





Product Nomenclature

Table 10. Part Numbering System :

Part Number Code	Description	Part Number	Value
X ₁	Company	S	Seoul Semiconductor
X ₂	Level of Integration	1	Discrete LED
X ₃ X ₄	Technology	CH	Color Horticulture
X ₅ X ₆ X ₇ X ₈	Dimension	3535	
X ₉ X ₁₀	Wavelength	45 47	455 470
X ₁₁ X ₁₂	Color	00	
X ₁₃ X ₁₄	Vf	03	
X ₁₅ X ₁₆ X ₁₇	Characteristic code Flux Rank	000	
X ₁₈ X ₁₉ X ₂₀	Characteristic code Vf Rank	000	
X ₂₁ X ₂₂	Characteristic code Color Step	00	
X ₂₃ X ₂₄	Type	00	
X ₂₅ X ₂₆ X ₂₇	Internal code	004	Z5M4



Handling of Silicone Resin for LEDs

- (1) During processing, mechanical stress on the surface should be minimized as much as possible. Sharp objects of all types should not be used to pierce the sealing compound.



- (2) In general, LED should only be handled from the side. By the way, this also applies to LED without a silicone sealant, since the surface can also become scratched.
- (3) When populating boards in SMT production, there are basically no restrictions regarding the form of the pick and place nozzle, except that mechanical pressure on the surface of the resin must be prevented. This is assured by choosing a pick and place nozzle which is larger than the LED's reflector area.
- (4) Silicone differs from materials conventionally used for the manufacturing of LEDs. These conditions must be considered during the handling of such devices. Compared to standard encapsulants, silicone is generally softer, and the surface is more likely to attract dust. As mentioned previously, the increased sensitivity to dust requires special care during processing. In cases where a minimal level of dirt and dust particles cannot be guaranteed, a suitable cleaning solution must be applied to the surface after the soldering of components.
- (5) Seoul Semiconductor suggests using isopropyl alcohol for cleaning. In case other solvents are used, it must be assured that these solvents do not dissolve the package or resin. Ultrasonic cleaning is not recommended. Ultrasonic cleaning may cause damage to the LED.
- (6) Please do not mold this product into another resin (epoxy, urethane, etc) and do not handle this product with acid or sulfur material in sealed space.
- (7) Avoid leaving fingerprints on silicone resin parts.



Precaution for Use

(1) Storage

To avoid the moisture penetration, we recommend storing LED in a dry box with a desiccant . The recommended storage temperature range is 5°C to 30°C and a maximum humidity of RH50%.

(2) Use Precaution after Opening the Packaging

Use SMD techniques properly when solder the LED as separation of the lens may affect the light output efficiency.

Pay attention to the following:

- a. Recommend conditions after opening the package
 - Sealing / Temperature : 5 ~ 30°C Humidity : less than RH60%
- b. If the package has been opened more than 4 weeks (**MSL 2a**) or the color of the desiccant changes, components should be dried for 10-24hr at 65±5°C

(3) Do not apply mechanical force or excess vibration during the cooling process to normal temperature after soldering.

(4) Do not rapidly cool device after soldering.

(5) Components should not be mounted on warped (non coplanar) portion of PCB.

(6) Radioactive exposure is not considered for the products listed here in.

(7) Gallium arsenide is used in some of the products listed in this publication. These products are dangerous if they are burned or shredded in the process of disposal. It is also dangerous to drink the liquid or inhale the gas generated by such products when chemically disposed of.

(8) This device should not be used in any type of fluid such as water, oil, organic solvent and etc. When washing is required, IPA (Isopropyl Alcohol) should be used.

(9) When the LED are in operation the maximum current should be decided after measuring the package temperature.

(10) The appearance and specifications of the product may be modified for improvement without notice.

(11) Long time exposure of sunlight or occasional UV exposure will cause lens discoloration.



Precaution for Use

(12) VOCs (Volatile organic compounds) emitted from materials used in the construction of fixtures can penetrate silicone encapsulants of LED and discolor when exposed to heat and photonic energy. The result can be a significant loss of light output from the fixture. Knowledge of the properties of the materials selected to be used in the construction of fixtures can help prevent these issues.

(13) Attaching LEDs, do not use adhesives that outgas organic vapor.

(14) The driving circuit must be designed to allow forward voltage only when it is ON or OFF. If the reverse voltage is applied to LED, migration can be generated resulting in LED damage.

(15) LED is sensitive to Electro-Static Discharge (ESD) and Electrical Over Stress (EOS). Below is a list of suggestions that Seoul Semiconductor purposes to minimize these effects.

a. ESD (Electro Static Discharge)

Electrostatic discharge (ESD) is defined as the release of static electricity when two objects come into contact. While most ESD events are considered harmless, it can be an expensive problem in many industrial environments during production and storage. The damage from ESD to an LED may cause the product to demonstrate unusual characteristics such as:

- Increase in reverse leakage current lowered turn-on voltage
- Abnormal emissions from the LED at low current

The following recommendations are suggested to help minimize the potential for an ESD event.

One or more recommended work area suggestions:

- Ionizing fan setup
- ESD table/shelf mat made of conductive materials
- ESD safe storage containers

One or more personnel suggestion options:

- Antistatic wrist-strap
- Antistatic material shoes
- Antistatic clothes

Environmental controls:

- Humidity control (ESD gets worse in a dry environment)



Precaution for Use

b. EOS (Electrical Over Stress)

Electrical Over-Stress (EOS) is defined as damage that may occur when an electronic device is subjected to a current or voltage that is beyond the maximum specification limits of the device.

The effects from an EOS event can be noticed through product performance like:

- Changes to the performance of the LED package
(If the damage is around the bond pad area and since the package is completely encapsulated the package may turn on but flicker show severe performance degradation.)
- Changes to the light output of the luminaire from component failure
- Components on the board not operating at determined drive power

Failure of performance from entire fixture due to changes in circuit voltage and current across total circuit causing trickle down failures. It is impossible to predict the failure mode of every LED exposed to electrical overstress as the failure modes have been investigated to vary, but there are some common signs that will indicate an EOS event has occurred:

- Damaged may be noticed to the bond wires (appearing similar to a blown fuse)
- Damage to the bond pads located on the emission surface of the LED package
(shadowing can be noticed around the bond pads while viewing through a microscope)
- Anomalies noticed in the encapsulation and phosphor around the bond wires.
- This damage usually appears due to the thermal stress produced during the EOS event.

c. To help minimize the damage from an EOS event Seoul Semiconductor recommends utilizing:

- A surge protection circuit
- An appropriately rated over voltage protection device
- A current limiting device



Company Information

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Company Information

Seoul Semiconductor (www.SeoulSemicon.com) manufactures and packages a wide selection of light emitting diodes (LEDs) for the automotive, general illumination/lighting, Home appliance, signage and back lighting markets. The company is the world's fifth largest LED supplier, holding more than 10,000 patents globally, while offering a wide range of LED technology and production capacity in areas such as "nPola", "Acrich", the world's first commercially produced AC LED, and "Acrich MJT - Multi-Junction Technology" a proprietary family of high-voltage LEDs.

The company's broad product portfolio includes a wide array of package and device choices such as Acrich and Acirch2, high-brightness LEDs, mid-power LEDs, side-view LEDs, and through-hole type LEDs as well as custom modules, displays, and sensors.

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